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## NCE P-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE60P04Y uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge .This device is well suited for use as a load switch or in PWM applications.

#### **General Features**

•  $V_{DS} = -60V, I_{D} = -4A$ 

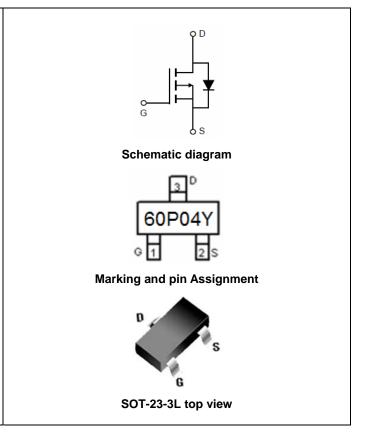
 $R_{DS(ON)}$  <120m $\Omega$  @  $V_{GS}$ =-10V

 $R_{DS(ON)}$  <170m $\Omega$  @  $V_{GS}$ =-4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## **Application**

- Load switch
- PWM application



## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
60P04Y	NCE60P04Y	SOT-23-3L	Ø180mm	8 mm	3000 units

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-60	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	-4	А
Pulsed Drain Current	I <sub>DM</sub>	-12	А
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup>	$R_{\theta JA}$	83.3	°C/W
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# NCE60P04Y

# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA -60		-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-60V,V <sub>GS</sub> =0V -		-	-1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-1.5	-2.2	-3.0	V	
Drain-Source On-State Resistance		V <sub>GS</sub> =-10V, I <sub>D</sub> =-4A	-	106	120	mΩ	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3A	-	135	170	mΩ	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4A	-	10	-	S	
Dynamic Characteristics (Note4)	·						
Input Capacitance	C <sub>lss</sub>	\/ 00\/\/ 0\/	-	930	-	PF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =-30V, $V_{GS}$ =0V, F=1.0MHz	-	85	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIDZ	-	35	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-30V, $R_L$ =7.5 $\Omega$ ,	-	4	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_G$ =3 $\Omega$	-	32	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	7	-	nS	
Total Gate Charge	Qg	V 201 4A	-	25	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-30, $I_{D}$ =-4A,	-	3	-	nC	
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-10V	-	7	-	nC	
Drain-Source Diode Characteristics	1						
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =-4A	-		-1.2	V	
Diode Forward Current (Note 2)	Is		-	-	-4	Α	
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =- 4A	-	25		nS	
Reverse Recovery Charge	Qrr	$di/dt = -100A/\mu s^{(Note3)}$	-	31		nC	

## Notes:

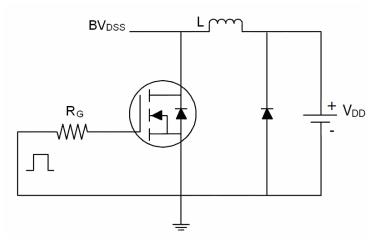
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

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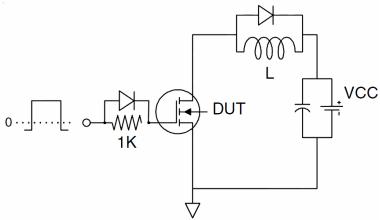


## **Test Circuit**

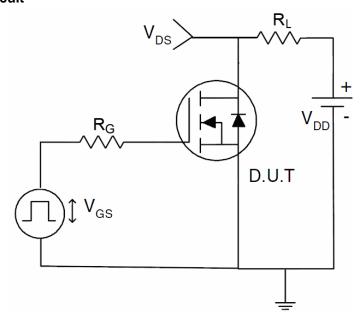
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit



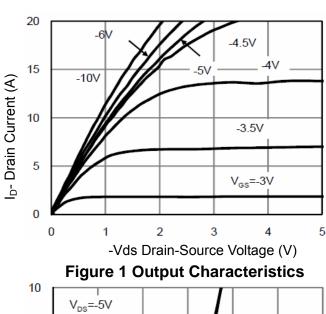
## 3) Switch Time Test Circuit

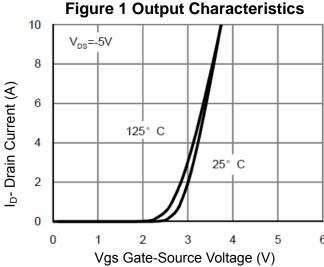


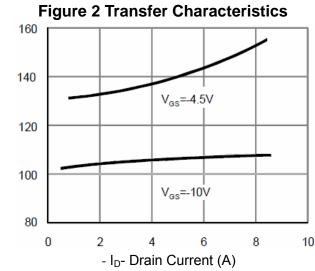
**Pb Free Product** 



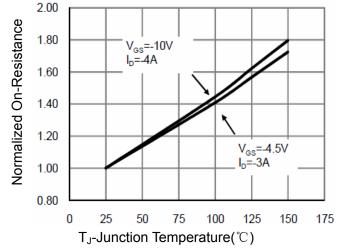
## **Typical Electrical and Thermal Characteristics (Curves)**



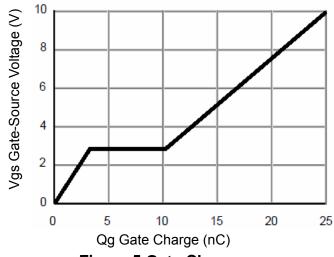


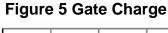












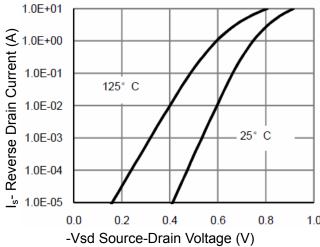


Figure 6 Source- Drain Diode Forward



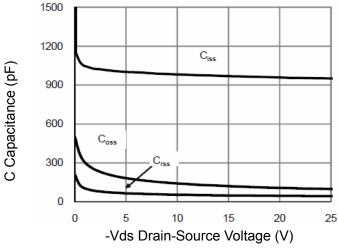
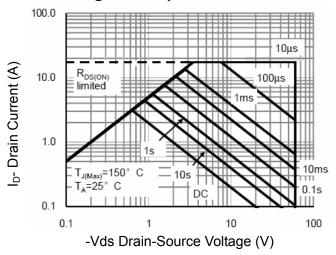
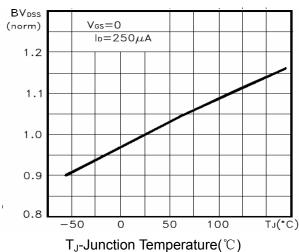


Figure 7 Capacitance vs Vds



**Figure 8 Safe Operation Area** 



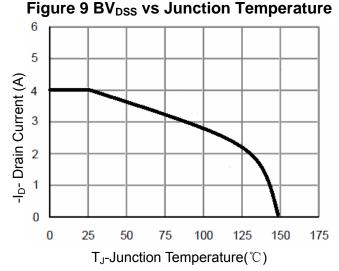
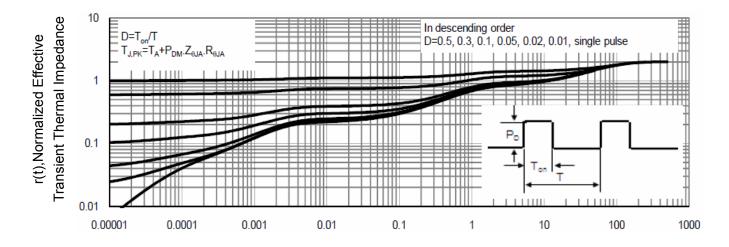


Figure 10 ID Current De-rating

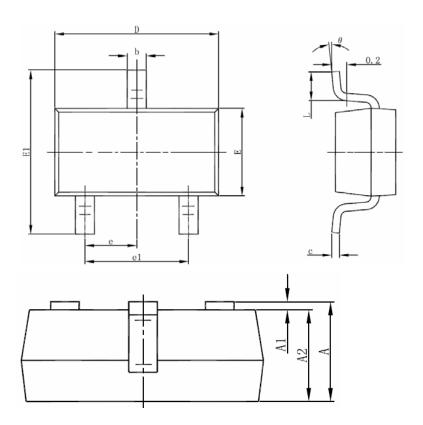


Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23-3L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



#### http://www.ncepower.com

NCE60P04Y

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